Wafer Connector pitch 1mm series

1. Scope

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This specification covers the Wafer Connector FWF10001/FWF10002 Series

2. Ordering information

Refer to the drawing.

3. Connector dimensions

Refer to the drawing.

4. Material

Housing: PA9T (UL 94V-0)

Color: Natural
Terminal: Copper alloy
Plating: Tin plated
Solder tab: Copper alloy
Plating: Tin plated

5. Accommodated P.C.B layout

Refer to the drawing.

6. Rating

Operating voltage(Max.) 50V AC/DC Current rating(Max.) 1.0A AC/DC

Temperature range-operating -25°C -- +85°C(Including terminal temperature rese)

7. Performance

Test item	Requirement	Test Condition		
Electrical Performance				
Contact Resistance		Mate connectors, measure by dry circuit, 20mV Max., 10mA. Mated Length: 50mm (AWG. #28) (Based upon JIS C5402 5.4)		
Insulation Resistance	100 MΩ Min.	Mate connectors, apply 500V DC between adjacent terminals or ground. (Based upon JIS C5402 5.2/MIL-STD-202 method 302 Cond.B)		
Dielectric Strength	No breakdown and flashove	Mate connectors, apply 500V AC for 1 minute between adjacent terminal or ground. (Based upon JIS C5402 5.1/MIL-STD-202 Method 301)		



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Test item	Requirement					Test Condition		
Contact resistance on crimped portion	10mΩ Max.					Crimp the maximum applicable wire on to the terminal, measure by dry circuit, 20mV MAX., 10mA. Wire Length: 50mm (AWG. #28)		
	1		М	echani	cal Pe	rformance		
Insertion force and withdrawal force	Refer to paragraph 9					Insert and withdraw connectors at a speed of 25± 3mm/minute.		
	Wire size #28 #30 #32			#30	#32			
		width		0.7±0.1				
	1	height	0.58~ 0.62	0.55~ 0.60	0.45~ 0.58			
Crimping pull out force	2	width height	1.10	0.70 1.00	0.90	Fix the crimped terminal, apply axial pull out force on the wire at a speed of 25±3mm/minute. (Based upon JIS C5402 6.22)		
			0.5kg min.					
	1. Conductor (mm) 2: Insulation (mm)							
Terminal Insertion Force	0.5kgf Max.					Insert the crimped terminal into the housing at a speed of 25± 3mm/min.		
Terminal/ Housing retention force	0.5kgf Min.					Apply axial pull out force at a speed of 25±3mm/minute on the terminal assembled In the housing.		
Pin Retention Force	0.5kgf Min.					Apply axial push force at a speed of 25±3mm/minute on the contact pin assembled in the base wafer.		
		Er	vironn	nental l	Perforr	nance and others		
Repeated Insertion and Withdrawal	Contact Resistance 40mΩ Max.			Mate connector up to 30 cycles repeatedly at a rate of 10 cycles/ minute. After which test the contact resistance.				
Temperature Rise	30°C Max.					Apply rated current load on mated connector in series- connection. Measure change of temperature on contact using thermocouples for 4 hours. (Based upon UL 1977)		
Vibration	Appearance No Damage			mage		Amplitude: 1.52mm P.P Sweep time: 10-55-10Hz/minute Duration: 2 hours in each X、Y、Z axlals. (Based upon MIL-STD-202 method 201A)		
	Contact Resistance 40mΩ Max.			Max.				
	Discontinuity 1µ sec Max.			: Max.				

STANDARD	SPECIFICATION



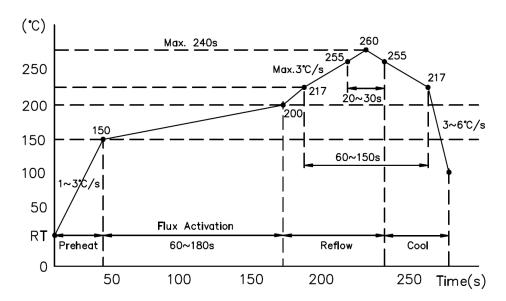
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Test item	Requirement		Test Condition	
Shock	Appearance	No Damage		
	Contact Resistance	40mΩ Max.	50G, 3 strokes in each X、Y、Z. axlals. (Based upon JIS C0041)	
	Discontinuity	1μ sec Max.		
	Appearance	No Damage	Mated connector shall be placed in an oven for 96±4 hours at	
Heat resistance	Contact Resistance	40mΩ Max.	+85±2°C. (Based upon JIS C5402 7.8)	
Cold resistance	Appearance	No Damage	Mated connector shall be placed in a temperature chamber for 96±4 hours at -25±2°C	
Cold resistance	Contact Resistance	40mΩ Max.	(Based upon JIS C5402 7.9)	
	Appearance	No Damage	Material connector shall be placed in a humidity shamber on	
Llumidity	Contact Resistance	40mΩ Max.	Mated connector shall be placed in a humidity chamber on the following conditions. Temperature: 40±2°C	
Humidity	Dielectric Strength	500V,AC/min	Relative humidity: 90~95% Duration: 240 Hours (Resed upon MIL STD 202 Method 103 Cond A)	
	Insulation Resistance	10MΩ Min.	(Based upon MIL-STD-202 Method 103 Cond.A)	
	Appearance	No Damage	Mated connector shall be set to temperature cycling for 5	
Tomporature evoling	Contact Resistance	40mΩ Max.	cycles of which 1 cycle consists of: 1>.+25°C ~ 3 minutes 2>25°C ~ 30 minutes	
Temperature cycling	Dielectric Strength	500V,AC/min	3>.+25°C ~ 30 minutes 4>.+85°C ~ 30 minutes	
	Insulation Resistance	10MΩ Min.	(Based upon JIS C5402 7.2)	
Salt Spray	Appearance	No Damage	Mated connector shall be placed in a salt spray chamber on the following conditions. Salt Solution Density: 5±1%	
	Contact Resistance	40mΩ Max.	Temperature: 35±2°C Duration: First punch, second plate: 24±4Hours First plate, second punch: 8±2Hours Remarks: we make sure the important area	
Solderability	95% of immersed area must show no voids nor pin holes.		Immerse fluxed soldered section of contact pin into a solder bath for 3±0.5sec Temperature: 230±5°C	
Resistance to soldering heat	No Damage in appearance		Mated connector shall be dipped on solder bath for 5±0.5sec Temperature: 260±5°C	

STANDARD	SPECIFI	CATION



8. Reference infrared reflow condition



Standard JEDEC temperature profile (Lead free reflow)

9. Insertion force and withdrawal force

(Unit:kgf)

Circuits	Insertion (Max.)	Withdrawal (Min.)		
Circuits	Initial	Initial	30th	
2	2.04	0.20	0.20	
3	2.04	0.20	0.20	
4	2.04	0.20	0.20	
5	3.06	0.30	0.30	
6	3.06	0.30	0.30	
7	3.06	0.30	0.30	
8	4.08	0.40	0.40	
9	4.08	0.40	0.40	
10	4.08	0.40	0.40	
11	5.10	0.50	0.50	
12	5.10	0.50	0.50	
13	5.10	0.50	0.50	
14	6.12	0.60	0.60	
15	6.12	0.60	0.60	
16	6.12	0.60	0.60	
17	7.14	0.70	0.70	
18	7.14	0.70	0.70	
19	7.14	0.70	0.70	
20	8.16	0.80	0.80	